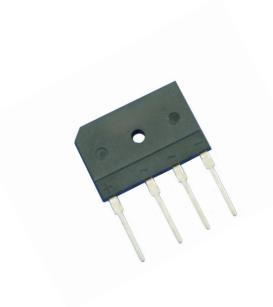
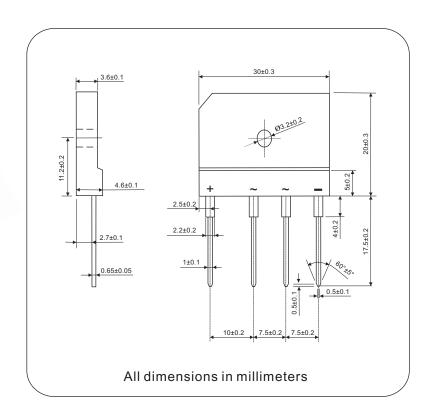
Nell High Power Products

Avalanche Glass Passivated Single-Phase Bridge Rectifier 15A/600V





FEATURES







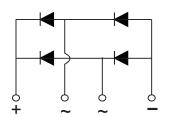
- Typical IR less than 0.50 μA
- High surge current capability
- Glass passivated chip junction
- Low forward voltage drop
- Low thermal resistance
- Compliant to RoHS
- Isolation voltage up to 2500V
- Controlled avalanche series

TYPICAL APPLICATIONS

General purpose use in AC/DC bridge full wave rectification for switching power supply, field supply for DC motor, home appliances, white-goods applications, power supply for Telecom, desktop PC and server switching mode power supply.



- International standard package Epoxy meets UL 94 V-O flammability rating
- Small volume, light weight
- Small thermal resistance
- High heat-conduction rate
- Low temperature rise
- High temperature soldering guaranteed : 260°C/10 second, 2.3kg tension force
- Weight: 6.5g (0.23 ozs)



PRIMARY CHARACTERRISTICS			
I _{F(AV)}	15A		
V _{RRM}	650V to 1100V		
I _{FSM}	350A		
I _R	0.20 μA, typical		
V _F	0.92V Max		
T _{J max} .	150°C		



Nell High Power Products

MAJOR RATINGS AND CHARACTERISTICS (T _A = 25°C unless otherwise noted)						
PARAMETER	SYMBOL	GBJ1506A	UNIT			
Minimum repetitive peak reverse voltage	V _{RRM}	600	V			
Peak reverse non-repetitive voltage	V _{RSM}	700	V			
Minimum avalanche breakdown voltage at 10μA	V _{BR}	650	V			
Maximum avalanche breakdown voltage at 10µA	V _{BR}	1100	V			
Maximum average forward rectified output current, T _c = 125°C	I _{F(AV)}	15	А			
Peak forward surge current single sine-wave superimposed on rated load	I _{FSM}	350	А			
Rating (non-repetitive, for t greater than 1 ms and less than 8.3 ms) for fusing	I ² t	508	A ² s			
RMS isolation voltage from case to leads	V _{ISO}	2500	V			
Operating junction storage temperature range	TJ	-40 to 150	°C			
Storage temperature range	T _{STG}	-40 to 150	°C			

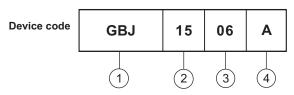
ELECTRICAL CHARACTERISTICS (T _A = 25°C unless otherwise noted)						
PARAMETER	TEST CONDITIONS	SYMBOL	GBJ1506A		UNIT	
			TYP.	MAX.		
Instantaneous forward drop per diode	I _F = 7.5A	V _F	0.88	0.92	V	
Maximum reverse DC current at rated DC blocking voltage per diod	T _A = 25°C	I _R	0.2	2.0	μА	
	T _A = 125°C		50	-		

THERMAL AND MECHANICAL (T _A = 25°C unless otherwise noted)							
PARAMETER	TEST CONDITIONS	SYMBOL	GBJ1506A	UNIT			
Typical thermal resistance junction to case	Single-side heat dissipation, sine half wave	R _{0JC} ⁽¹⁾	0.8	°C/W			
Mounting torque to heatsink M3 ± 10 %	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound.		0.8	N·m			
Approximate weight			6.5	g			

Notes

(1) With heatsink, single side heat dissipation, half sine wave.

Ordering Information Tabel



1 - Product type : "GBJ" Package,1Ø Bridge

2 - I_{F(AV)} rating: "15" for 15A

3 - Voltage code : code x 100 = V_{RRM}

- "A" for avalanche type, Minimum avalanche breakdown voltage = V_{RRM} + 50V Maximum avalanche breakdown voltage = V_{RRM} + 500V



Nell High Power Products

Fig.1 Derating curve for output rectified current

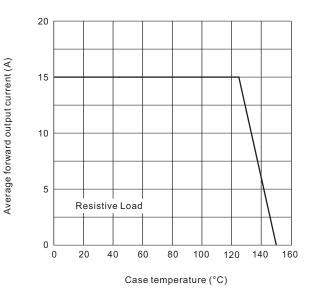


Fig.2 Maximum non-repetitive peak forward surge current per bridge element

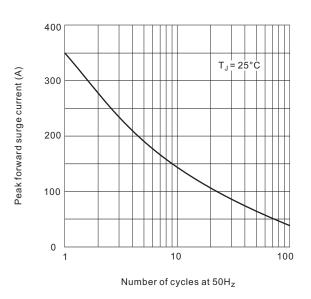


Fig.3 Typical reverse characteristics per bridge element

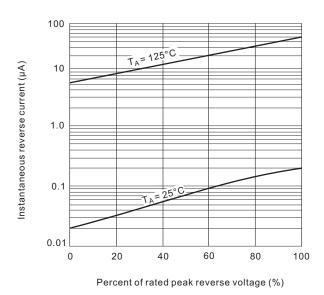


Fig.4 Typical forward characteristics per bridge element

